



# Phase Dimmable PSR LED Driver IC for LED Lighting

MB39C603 is a Primary Side Regulation (PSR) LED driver IC for LED lighting. Using the information of the primary peak current and the transformer-energy-zero time, it is able to deliver a well regulated current to the secondary side without using an opto-coupler in an isolated flyback topology. Operating in critical conduction mode, a smaller transformer is required. In addition, MB39C603 has a built-in phase dimmable circuit and can constitute flicker less lighting systems for phase dimming with low-component count. It is most suitable for the general lighting applications, for example replacement of commercial and residential incandescent lamps.

#### **Features**

- ■PSR topology in an isolated flyback circuit
- High power factor (>0.9: without dimmer) in Single Conversion
- High efficiency (>80%: without dimmer) and low EMI by detecting transformer zero energy
- ■Built-in phase dimmable circuit
  - □ Dimming curve based on conduction angle
  - □ Dimmer hold current control
- Highly reliable protection functions
- ☐ Under voltage lock out (UVLO)
- ☐ Over voltage protection (OVP)
- □ Over current protection (OCP)
- ☐ Over temperature protection (OTP)
- Switching frequency setting: 30 kHz to 133 kHz
- ■Input voltage range VDD: 9V to 20V
- ■Input voltage for LED lighting applications: AC110V<sub>RMS</sub>
- ■Output power range for LED lighting applications: 15W to 50W
- Package: SOP-14 (5.30 mm × 10.15 mm × 2.25 mm[Max])

### **Applications**

- ■Phase dimmable (Leading/Trailing) LED lighting
- ■LED lighting



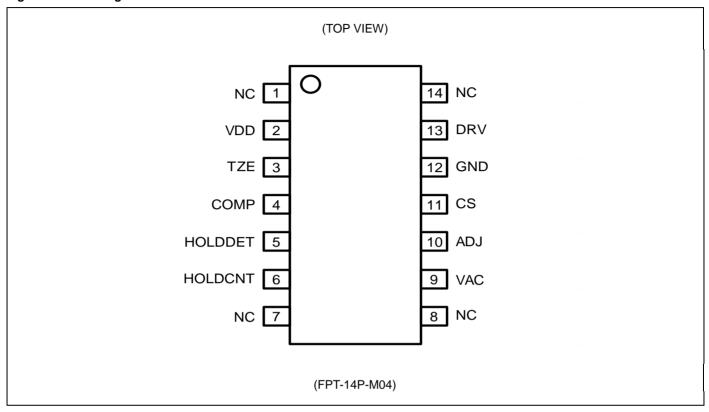
## **Contents**

1.	Pin Assignment	3
2.	Pin Descriptions	3
3.	Block Diagram	4
4.	Absolute Maximum Ratings	5
5.	Recommended Operating Conditions	6
6.	Electrical Characteristics	7
7.	Standard Characteristics	9
8.	Function Explanations	10
8.1	LED Current Control by PSR(Primary Side Regulation)	10
8.2	PFC (Power Factor Correction) Function	11
8.3	Phase Dimming Function	11
8.4	HOLD Current Control Function	12
8.5	Power-On Sequence	13
8.6	Power-Off Sequence	14
8.7	I <sub>P_PEAK</sub> Detection Function	14
8.8	Zero Voltage Switching Function	14
8.9	Protection Functions	15
9.	I/O Pin Equivalent Circuit Diagram	16
10.	Application Examples	18
10.1	17W Isolated and Phase Dimming Application	18
11.	Usage Precautions	26
12.	Ordering Information	27
13.	Marking Format	27
14.	Recommended Mounting Condition [JEDEC Level3] Lead Free	28
14.1	Recommended Reflow Condition	28
14.2	Reflow Profile	28
15.	Package Dimensions	29
16.	Major Changes	30
Docu	ument History	31



## 1. Pin Assignment

Figure 1-1 Pin Assignment



## 2. Pin Descriptions

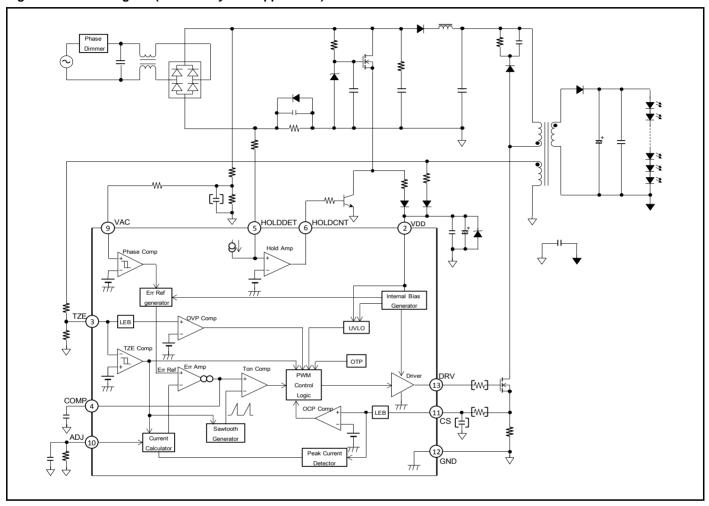
**Table 2-1 Pin Descriptions** 

Pin No.	Pin Name	I/O	Description
1	NC	-	Not used. Leave this pin open.
2	VDD	-	Power supply pin.
3	TZE	I	Transformer Zero Energy detecting pin.
4	COMP	0	External Capacitor connection pin for the compensation.
5	HOLDDET	I	Phase Dimmer current detecting pin.
6	HOLDCNT	0	External BIP base current control pin.
7	NC	-	Not used. Leave this pin open.
8	NC	-	Not used. Leave this pin open.
9	VAC	I	Phase Dimmer conduction angle detecting pin.
10	ADJ	0	Pin for adjusting the switch-on timing.
11	CS	1	Pin for detecting peak current of transformer primary winding.
12	GND	-	Ground pin.
13	DRV	0	External MOSFET gate connection pin.
14	NC	-	Not used. Leave this pin open.



## 3. Block Diagram

Figure 3-1 Block Diagram (Isolated Flyback Application)





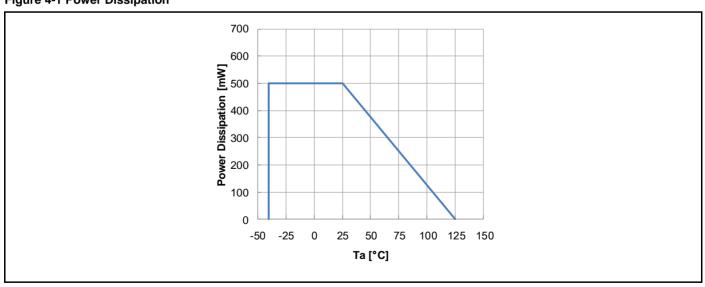
## 4. Absolute Maximum Ratings

**Table 4-1 Absolute Maximum Ratings** 

Davamatar	Cumahad	Condition	Ra	ting	l lm!t
Parameter	Symbol	Symbol Condition		Max	Unit
Power Supply Voltage	Power Supply Voltage V <sub>VDD</sub> VDD pi		-0.3	+25	V
	V <sub>CS</sub>	CS pin	-0.3	+6.0	V
Innut Valtage	V <sub>TZE</sub>	TZE pin	-0.3	+6.0	V
Input Voltage	V <sub>HOLDDET</sub>	HOLDDET pin	-0.3	+6.0	V
	V <sub>VAC</sub>	VAC pin	-0.3	+6.0	V
Output Valtage	$V_{DRV}$	DRV pin	-0.3	+25	V
Output Voltage	V <sub>HOLDCNT</sub>	HOLDCNT pin	-0.3	+6.0	V
	I <sub>ADJ</sub>	ADJ pin	-1	-	mA
Output Current	I <sub>DRV</sub>	DRV pin DC level	-50	+50	mA
	I <sub>HOLDCNT</sub>	HOLDCNT pin	-400	-	μA
Power Dissipation	P <sub>D</sub>	Ta ≤ +25°C	-	500(*1)	mW
Storage Temperature	T <sub>STG</sub>	-	-55	+125	°C
ESD Voltage 1	SD Voltage 1 V <sub>ESDH</sub> Human Body Model		-2000	+2000	V
ESD Voltage 2	V <sub>ESDC</sub>	Charged Device Model	-1000	+1000	V

<sup>\*1:</sup> The value when using two layers PCB.
Reference: θja (wind speed 0m/s): 200°C/W

**Figure 4-1 Power Dissipation** 



### **WARNING:**

1. Semiconductor devices may be permanently damaged by application of stress (including, without limitation, voltage, current or temperature) in excess of absolute maximum ratings. Do not exceed any of these ratings.



## 5. Recommended Operating Conditions

**Table 5-1 Recommended Operating Conditions** 

Dovemeter	Symbol	Condition	Value			
Parameter	Symbol	Condition	Min	Тур	Max	Unit
VDD pin Input Voltage	$V_{VDD}$	VDD pin	9	-	20	V
VAC pin Resistance	R <sub>VAC</sub>	VAC pin	-	510	-	kΩ
TZE pin Resistance	R <sub>TZE</sub>	TZE pin	50	-	200	kΩ
ADJ pin Resistance	R <sub>ADJ</sub>	ADJ pin	9.3	-	185.5	kΩ
COMP pin Capacitance	Ссомр	COMP pin	-	4.7	-	μF
VDD pin Capacitance	СвР	Set between VDD pin and GND pin	-	100	-	μF
Operating Junction Temperature	Tj	-	-40	-	+125	°C

#### WARNING:

- 1. The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated under these conditions.
- 2. Any use of semiconductor devices will be under their recommended operating condition.
- 3. Operation under any conditions other than these conditions may adversely affect reliability of device and could result in device failure.
- 4. No warranty is made with respect to any use, operating conditions or combinations not represented on this data sheet. If you are considering application under any conditions other than listed herein, please contact sales representatives beforehand.



## 6. Electrical Characteristics

### **Table 6-1 Electrical Characteristics**

 $(Ta = +25^{\circ}C, V_{VDD} = 12V)$ 

Parameter		Symbol	Pin	Condition	Value			Unit
raid	anietei	Symbol	FIII	Condition	Min	Тур	Max	Oilit
	UVLO Turn-on threshold voltage	$V_{TH}$	VDD	-	9.6	10.2	10.8	V
UVLO	UVLO Turn-off threshold voltage	$V_{TL}$	VDD	-	7.55	8	8.5	٧
	Startup current	I <sub>START</sub>	VDD	V <sub>VDD</sub> = 7V	-	65	160	μA
	Zero energy threshold voltage	$V_{TZETL}$	TZE	TZE = "H" to "L"	-	20	-	mV
	Zero energy threshold voltage	V <sub>TZETH</sub>	TZE	TZE = "L" to "H"	0.6	0.7	0.8	V
TRANSFORMER ZERO ENERGY	TZE clamp voltage	V <sub>TZECLAMP</sub>	TZE	I <sub>TZE</sub> = -10 μA	-200	-160	-100	mV
DETECTION	OVP threshold voltage	$V_{TZEOVP}$	TZE	-	4.15	4.3	4.45	<b>V</b>
	OVP blanking time	t <sub>OVPBLANK</sub>	TZE	-	0.6	1	1.7	μs
	TZE input current	I <sub>TZE</sub>	TZE	V <sub>TZE</sub> = 5V	-1	-	+1	μA
COMPENSATION	Source current	I <sub>SO</sub>	COM P	V <sub>COMP</sub> = 2V, V <sub>CS</sub> = 0V, Conduction Angle = 165deg	-	-27	-	μA
	Trans conductance	gm	COM P	$V_{COMP} = 2.5V$ , $V_{CS} = 1V$	-	96	-	μΑ/ V
	ADJ voltage	$V_{ADJ}$	ADJ	-	1.81	1.85	1.89	>
AD II ICTMENT	ADJ source current	I <sub>ADJ</sub>	ADJ	V <sub>ADJ</sub> = 0V	-650	-450	-250	μA
ADJUSTMENT	ADJ time	t <sub>ADJ</sub>	TZE DRV	$t_{ADJ}$ (R <sub>ADJ</sub> = 51 k $\Omega$ ) - $t_{ADJ}$ (R <sub>ADJ</sub> = 9.1 k $\Omega$ )	490	550	610	ns
	Minimum switching period	T <sub>SW</sub>	TZE DRV	-	6.75	7.5	8.25	μs
	OCP threshold voltage	V <sub>OCPTH</sub>	CS	-	1.9	2	2.1	٧
CURRENT SENSE	OCP delay time	tocpdly	CS	-	-	400	500	ns
	CS input current	I <sub>cs</sub>	cs	V <sub>CS</sub> = 5V	-1	-	+1	μA



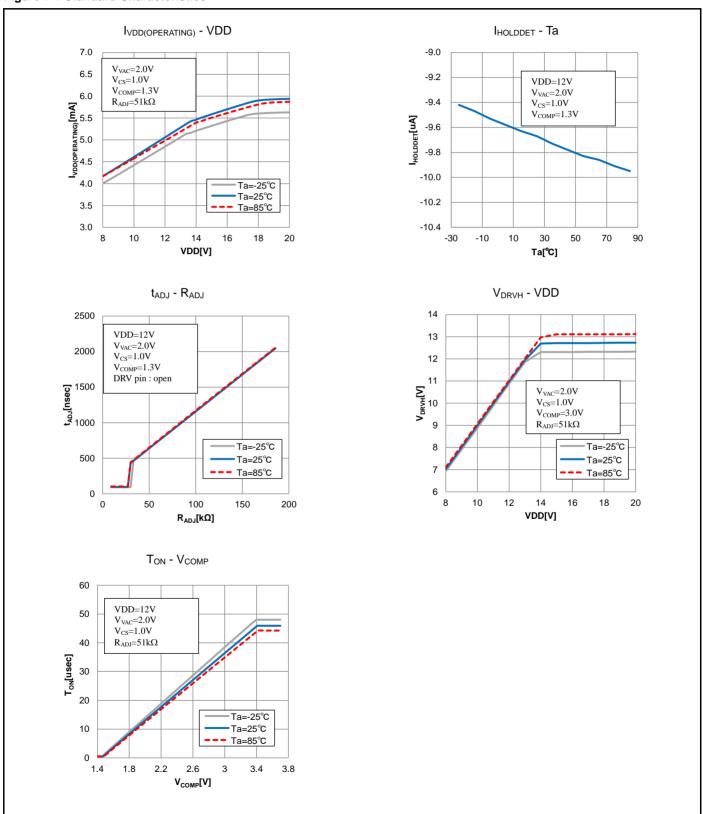
 $(Ta = +25^{\circ}C, V_{VDD} = 12V)$ 

Parameter		Currely of	Di-	Condition		Unit		
Pai	rameter	Symbol	Pin	Condition	Min	Тур	Max	Unit
	DRV high voltage	V <sub>DRVH</sub>	DRV	VDD = 18V, I <sub>DRV</sub> = -30 mA	7.6	9.4	ı	V
	DRV low voltage	$V_{DRVL}$	DRV   VDD = 18V, I <sub>DRV</sub> = 30 mA		1	130	260	mV
	Rise time	t <sub>RISE</sub>	DRV	VDD = 18V, CLOAD = 1 nF	-	94	1	ns
DRV	Fall time	t <sub>FALL</sub>	DRV	VDD = 18V, CLOAD = 1 nF		16	,	ns
DRV	Minimum on time	t <sub>ONMIN</sub>	DRV	TZE trigger	300	500	700	ns
	Maximum on time	t <sub>ONMAX</sub>	DRV	-	27	44	60	μs
	Minimum off time	t <sub>OFFMIN</sub>	DRV	-	1	1.5	1.93	μs
	Maximum off time	t <sub>OFFMAX</sub>	DRV	TZE = GND	37	46	55	μs
OTP	OTP threshold	T <sub>OTP</sub>	-	Tj, temperature rising	-	150	ı	°C
OIF	OTP hysteresis	T <sub>OTPHYS</sub>	-	Tj, temperature falling, degrees below T <sub>OTP</sub>	-	25	•	°C
DIMMER	Phase Comp threshold voltage	V <sub>PHTH1</sub>	VAC	VAC = "L" to "H"	0.9	1.0	1.1	>
CONDUCTION ANGLE	Phase Comp threshold voltage	V <sub>PHTH2</sub>	VAC	VAC = "H" to "L"	0.45	0.5	0.55	٧
DETECTION	Phase Comp hysteresis	V <sub>PHHYS</sub>	VAC	-	-	0.5	-	V
	HOLDDET input current	IHOLDDET	HOLD DET	-	-10.0 9	-9.7	-9.32	μA
	Hold Amp threshold voltage	V <sub>HOLDTH</sub>	HOLD CNT	-	375	400	425	mV
TRIAC HOLD CURRENT CONTROL	HOLDCNT Maximum output voltage	V <sub>CNTOH</sub>	HOLD CNT	$\begin{aligned} &V_{\text{HOLDDET}} = 0.6V, \\ &R_{\text{BASE}} = 16 \text{ k}\Omega, \\ &V_{\text{BASE}} = 0.7V \end{aligned}$	3.4	-	-	٧
CONTROL	HOLDCNT Minimum output voltage	V <sub>CNTOL</sub>	HOLD CNT	$\begin{aligned} &V_{HOLDDET} = 0.2V, \\ &R_{BASE} = 16 \text{ k}\Omega, \\ &V_{BASE} = 0.7V \end{aligned}$			0.8	٧
	HOLDCNT source current	I <sub>CNTSO</sub>	HOLD CNT	$V_{HOLDDET} = 0.6V,$ $R_{BASE} = 16 \text{ k}\Omega,$ $V_{BASE} = 0.7V$	-250	-200	-167	μA
POWER	Power supply	I <sub>VDD(STATIC)</sub>	VDD	$V_{VDD} = 20V$ , $V_{TZE} = 1V$	-	3.3	4	mA
SUPPLY CURRENT	current	IVDD(OPERATING)	VDD	$V_{VDD} = 20V, Qg = 20 \text{ nC},$ $f_{SW} = 133 \text{ kHz}$	-	5.9	-	mA



### 7. Standard Characteristics

Figure 7-1 Standard Characteristics





### 8. Function Explanations

### 8.1 LED Current Control by PSR(Primary Side Regulation)

MB39C603 regulates the average LED current ( $I_{LED}$ ) by feeding back the information based on Primary Winding peak current ( $I_{P\_PEAK}$ ), Secondary Winding energy discharge time ( $T_{DIS}$ ) and switching period ( $T_{SW}$ ). Figure 8-1 shows the operating waveform in steady state.  $I_P$  is Primary Winding current and  $I_S$  is Secondary Winding current.  $I_{LED}$  as an average current of the Secondary Winding is described by the following equation.

$$I_{LED} = \frac{1}{2} \times I_{S\_PEAK} \times \frac{T_{DIS}}{T_{SW}}$$

Using  $I_{P\_PEAK}$  and the transformer Secondary to Primary turns ratio ( $N_P/N_S$ ), Secondary Winding peak current ( $I_{S\_PEAK}$ ) is described by the following equation.

$$I_{S\_PEAK} = \frac{N_P}{N_S} \times I_{P\_PEAK}$$

Therefore.

$$I_{LED} = \frac{1}{2} \times \frac{N_P}{N_S} \times I_{P\_PEAK} \times \frac{T_{DIS}}{T_{SW}}$$

MB39C603 detects  $T_{DIS}$  by monitoring the TZE pin and  $I_{P\_PEAK}$  by monitoring the CS pin and then controls  $I_{LED}$ . An internal Err Amp sinks gm current proportional to  $I_{P\_PEAK}$  from the COMP pin during  $T_{DIS}$  period. In steady state, since the average of the gm current is equal to internal reference current ( $I_{SO}$ ), the voltage on the COMP pin ( $V_{COMP}$ ) is nearly constant.

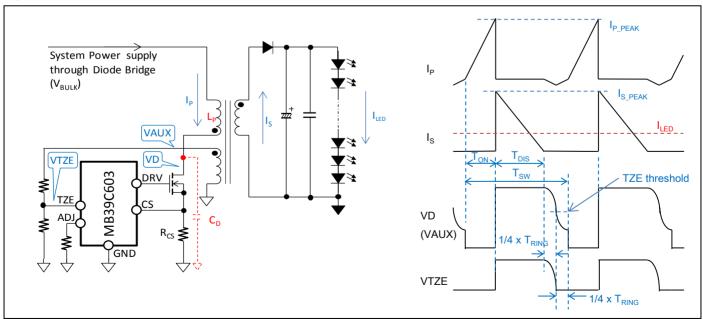
$$I_{P\ PEAK} \times R_{CS} \times gm \times T_{DIS} = I_{SO} \times T_{SW}$$

In above equation, gm is transconductance of the Err Amp and R<sub>CS</sub> is a sense resistance.

Eventually, I<sub>LED</sub> can be calculated by the following equation.

$$I_{LED} = \frac{1}{2} \times \frac{N_P}{N_S} \times \frac{I_{SO}}{gm} \times \frac{1}{R_{CS}}$$

Figure 8-1 LED Current Control Waveform





### 8.2 PFC (Power Factor Correction) Function

Switching on time ( $T_{ON}$ ) is generated by comparing  $V_{COMP}$  with an internal sawtooth waveform (refer to Figure 3-1). Since  $V_{COMP}$  is slow varying with connecting an external capacitor ( $C_{COMP}$ ) from the COMP pin to the GND pin,  $T_{ON}$  is nearly constant within an AC line cycle. In this state,  $I_{P\_PEAK}$  is nearly proportional to the AC line voltage ( $V_{BULK}$ ). It can bring the phase differences between the input voltage and the input current close to zero, so that high Power Factor can be achieved.

#### 8.3 Phase Dimming Function

MB39C603 is compatible with both leading-edge dimmers (TRIAC dimming) and trailing-edge dimmers.

To realize the phase dimming, this device has two functions, dimmer conduction angle detect function for LED current control and TRIAC dimmer hold current control function.

Figure 8-2 shows how MB39C603 detects the conduction angle.  $V_{BULK}$  is scaled via a resistor divider connected to the VAC pin. The conduction angle is detected by monitoring the voltage on the VAC pin ( $V_{VAC}$ ).

MB39C603 measures a half of power cycle period (Tpow) as duration between negative crossings of  $V_{VAC}$  and a Phase Comp threshold voltage ( $V_{PHTH2}$ ). Dimmer-ON period (Tdim) is measured as duration between a positive crossing of  $V_{VAC}$  and another Phase Comp threshold voltage ( $V_{PHTH1}$ ) and the following negative crossing. Conduction angle is defined as Tdim/Tpow × 180°.

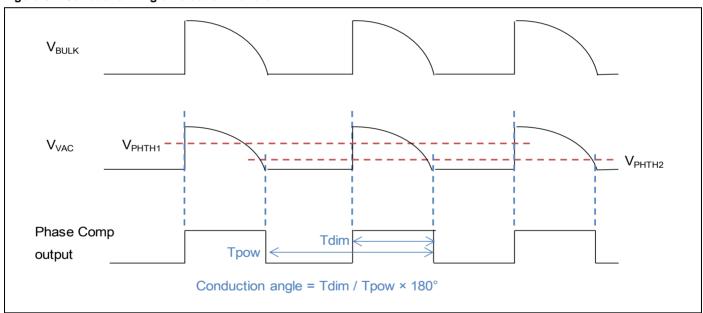


Figure 8-2 Conduction Angle Detection Waveform

MB39C603 regulates LED current by changing a reference of Err Amp as a function of the conduction angle. Table 8-1 shows I<sub>LED</sub> dimming ratio based on the conduction angle.

In addition, the initial I<sub>LED</sub> ratio in Power–On state is 5%.

Table 8-1 ILED Ratio Based on Conduction Angles

Conduction Angle	I <sub>LED</sub> Ratio [%]
θ < 45deg	5
45deg ≤ θ < 90deg	$(25/45) \times \theta - 20$
90deg ≤ θ < 135deg	$(70/45) \times \theta$ -110
135deg ≤ θ	100



#### 8.4 HOLD Current Control Function

The hold current control function prevents LEDs from flickering caused by shortage of hold current. The hold current ( $I_{HOLD}$ ) is the minimum current required to flow through TRIAC dimmer in order to keep the TRIAC on (refer to Figure 8-3). In small conduction angle, since  $I_{LED}$  can be low, AC/DC Converter current ( $I_{BULK}$ ) and TRIAC dimmer current ( $I_{TRIAC}$ ) are reduced. Once  $I_{TRIAC}$  falls below  $I_{HOLD}$ , TRIAC goes off and this results in LED flickering. MB39C603 controls  $I_{TRIAC}$  larger than  $I_{HOLD}$  by adding the current ( $I_{BIP}$ ) via a BIP transistor (M1) with sensing  $I_{TRIAC}$  and keeps the TRIAC on.

 $I_{TRIAC}$  is sensed with a resistor (R<sub>S</sub>). A bypass diode (D<sub>BYPASS</sub>) is used to clamp the voltage between R<sub>S</sub> terminals (V<sub>RS</sub>) and prevent the voltage on the HOLDDET pin (V<sub>HOLDDET</sub>) from exceeding absolute maximum ratings. An offset resistor (R<sub>OFFSET</sub>) is used to add an offset voltage to V<sub>HOLDDET</sub> and prevent V<sub>HOLDDET</sub> from the above ratings.

R<sub>S</sub> is set as the following equation.

$$R_S = \frac{R_{OFFSET} \times I_{HOLDDET} - V_{HOLDTH}}{I_{TRIACMIN}}$$

where I<sub>HOLDDET</sub> is the current of the HOLDDET pin, V<sub>HOLDTH</sub> is Hold Amp threshold voltage, and I<sub>TRIACMIN</sub> is minimum TRIAC current chosen by designers.

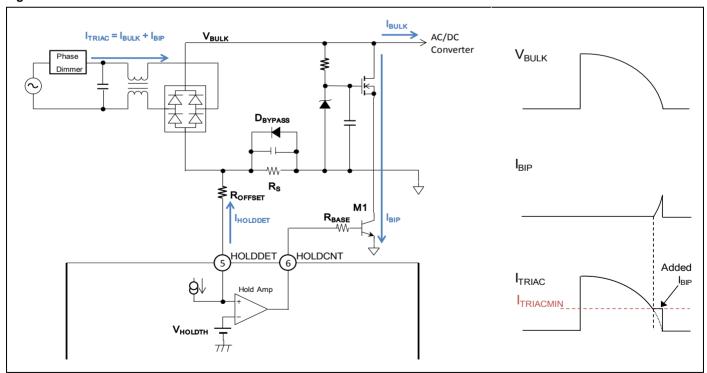
Roffset is set as the following equation.

$$R_{OFFSET} > \frac{V_{BYPASSMAX} - 0.3V}{I_{HOLDDET}}$$

where  $V_{\text{BYPASSMAX}}$  is the maximum forward voltage of  $D_{\text{BYPASS}}$ .

Hold Amp is designed only for driving BIP transistors. Connecting a resistor (R<sub>BASE</sub>) between the HOLDCNT pin and M1 base terminal limits the maximum I<sub>BIP</sub> value and clamp the rush current at TRIAC dimmer-on timing.

Figure 8-3 HOLD Current Control Waveform





#### 8.5 Power-On Sequence

When the AC line voltage is supplied,  $V_{BULK}$  is powered from the AC line through a diode bridge, and the VDD pin is charged from  $V_{BULK}$  through an external source-follower BiasMOS.(Figure 8-4 red path)

When the VDD pin is charged up and the voltage on the VDD pin ( $V_{VDD}$ ) rises above the UVLO threshold voltage, an internal Bias circuit starts operating, and MB39C603 starts the conduction angle detection (refer to 8.3). After the UVLO is released, this device enables switching and is operating in a forced switching mode ( $T_{ON} = 1.5 \mu s$ ,  $T_{OFF} = 78 \mu s$  to 320  $\mu s$ ). When the voltage on the TZE pin reaches the Zero energy threshold voltage ( $V_{TZETH} = 0.7V$ ), MB39C603 enters normal operation mode. After the switching begins, the VDD pin is also charged from Auxiliary Winding through an external diode (DBIAS).(Figure 8-4 blue path)

During non-conduction period  $V_{VDD}$  is not supplied from  $V_{BULK}$  or Auxiliary Winding. It is necessary to set an appropriate capacitor of the VDD pin in order to keep  $V_{VDD}$  above the UVLO threshold voltage in this period. An external diode (D1) between BiasMOS and the VDD pin is used to prevent discharge from the VDD pin to  $V_{BULK}$  at zero cross points of the AC line voltage.

Figure 8-4 VDD Supply Path at Power-On

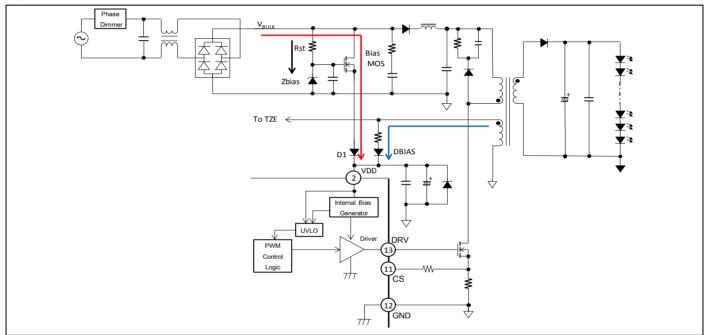
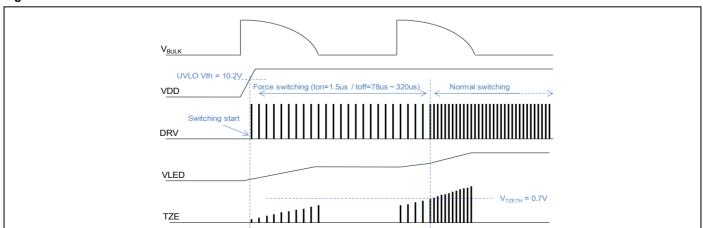


Figure 8-5 Power-On Waveform

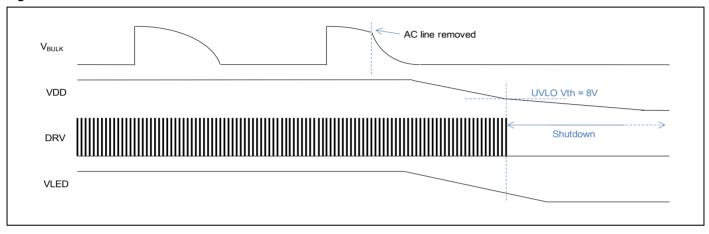




#### 8.6 Power-Off Sequence

After the AC line voltage is removed,  $V_{BULK}$  is discharged by switching operation and the Hold current circuit. Since any Secondary Winding current does not flow,  $I_{LED}$  is supplied only from output capacitors and decreases gradually.  $V_{VDD}$  also decreases because there is no current supply from both Auxiliary Winding and  $V_{BULK}$ . When  $V_{VDD}$  falls below the UVLO threshold voltage, MB39C603 shuts down.

Figure 8-6 Power-Off Waveform



#### 8.7 I<sub>P PEAK</sub> Detection Function

MB39C603 detects Primary Winding peak current ( $I_{P\_PEAK}$ ) of Transformer.  $I_{LED}$  is set by connecting a sense resistance ( $R_{CS}$ ) between the CS pin and the GND pin. Maximum  $I_{P\_PEAK}$  ( $I_{P\_PEAKMAX}$ ) limited by Over Current Protection (OCP) can also be set with the resistance.

Using the Secondary to Primary turns ratio (N<sub>P</sub>/N<sub>S</sub>) and I<sub>LED</sub>, R<sub>CS</sub> is set as the following equation (refer to 8.1).

$$R_{CS} = \frac{N_P}{N_S} \times \frac{0.132}{I_{LED}}$$

In addition, using the OCP threshold voltage (VOCPTH) and RCS, IP\_PEAKMAX is calculated with the following equation.

$$I_{P\_PEAKMAX} = \frac{V_{OCPTH}}{R_{CS}}$$

#### 8.8 Zero Voltage Switching Function

MB39C603 has built-in zero voltage switching function to minimize switching loss of the external switching MOSFET. This device detects a zero crossing point through a resistor divider connected from the TZE pin to Auxiliary Winding. A zero energy detection circuit detects a negative crossing point of the voltage on the TZE pin to Zero energy threshold voltage (V<sub>TZETL</sub>). On-timing of switching MOSFET is decided with waiting an adjustment time (t<sub>ADJ</sub>) after the negative crossing occurs.

 $t_{ADJ}$  is set by connecting an external resistance ( $R_{ADJ}$ ) between the ADJ pin and the GND pin. Using Primary Winding inductance ( $L_P$ ) and the parasitic drain capacitor of switching MOSFET ( $C_D$ ),  $t_{ADJ}$  is calculated with the following equation.

$$t_{ADJ} = \frac{\pi \sqrt{L_P \times C_D}}{2}$$

Using t<sub>ADJ</sub>, R<sub>ADJ</sub> is set as the following equation.

$$R_{ADI}[k\Omega] = 0.0927 \times t_{ADI}[ns]$$



#### 8.9 Protection Functions

#### **Under Voltage Lockout Protection (UVLO)**

The under voltage lockout protection (UVLO) prevents IC from a malfunction in the transient state during  $V_{VDD}$  startup and a malfunction caused by a momentary drop of  $V_{VDD}$ , and protects the system from destruction/deterioration. An UVLO comparator detects the voltage decrease below the UVLO threshold voltage on the VDD pin, and then the DRV pin is turned to "L" and the switching stops. MB39C603 automatically returns to normal operation mode when  $V_{VDD}$  increases above the UVLO threshold voltage.

### **Over Voltage Protection (OVP)**

The over voltage protection (OVP) protects Secondary side components from an excessive stress voltage. If the LED is disconnected, the output voltage of Secondary Winding rises up. The output overvoltage can be detected by monitoring the TZE pin. During Secondary Winding energy discharge time,  $V_{TZE}$  is proportional to  $V_{AUX}$  and the voltage of Secondary Winding (refer to 8.1). When  $V_{TZE}$  rises higher than the OVP threshold voltage for 3 continues switching cycles, the DRV pin is turned to "L", and the switching stops (latch off). When  $V_{VDD}$  drops below the UVLO threshold voltage, the latch is removed.

#### **Over Current Protection (OCP)**

The over current protection (OCP) prevents inductor or transformer from saturation. The drain current of the external switching MOSFET is limited by OCP. When the voltage on the CS pin reaches the OCP threshold voltage, the DRV pin is turned to "L" and the switching cycle ends. After zero crossing is detected on the TZE pin again, the DRV pin is turned to "H" and the next switching cycle begins.

### **Over Temperature Protection (OTP)**

The over temperature protection (OTP) protects IC from thermal destruction. When the junction temperature reaches +150°C, the DRV pin is turned to "L", and the switching stops. It automatically returns to normal operation mode if the junction temperature falls back below +125°C.

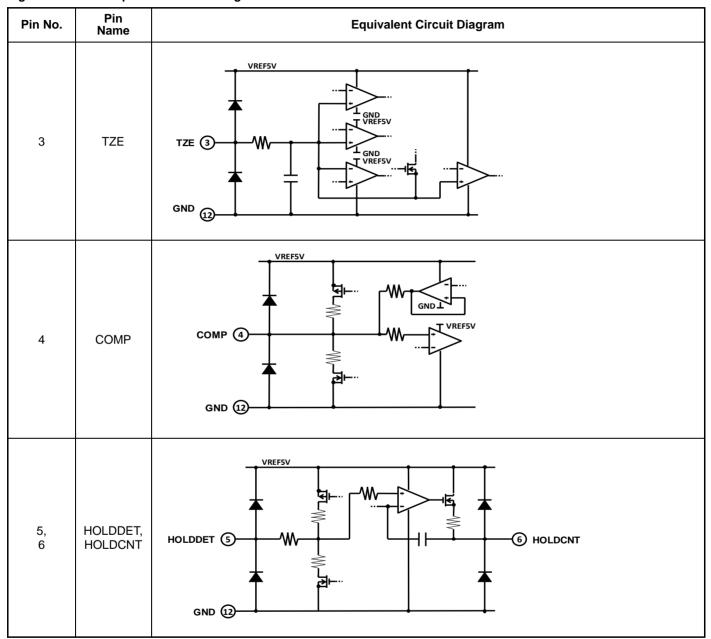
**Table 8-2 Protection Functions Table** 

Formation	PIN Operation				Detection	Return	Damada			
Function	DRV	HOLD CNT	COMP	ADJ	Condition	Condition	Remarks			
Normal Operation	Active	Active	Active Active		-					
Under Voltage Lockout Protection (UVLO)	L	L	L	L	VDD < 8V	VDD > 10.2V	Auto Restart			
Over Voltage Protection (OVP)	L	L	1.5V fixed	Active	TZE > 4.3V	VDD < 8V → VDD > 10.2V	Latch off			
Over Current Protection (OCP)	L	Active	Active	Active	CS > 2V	Cycle by cycle	Auto Restart			
Over Temperature Protection (OTP)	L	L	1.5V fixed	Active	Tj > +150°C Tj < +125°C		Auto Restart			



## 9. I/O Pin Equivalent Circuit Diagram

Figure 9-1 I/O Pin Equivalent Circuit Diagram





Pin No.	Pin Name	Equivalent Circuit Diagram
9	VAC	VAC 9  GND 12
10	ADJ	ADJ (10)  GND (12)
11	CS	CS (1)  VREF5V  GND (12)
13	DRV	VDD (2)  VREF5V  GND (12)



## 10. Application Examples

## 10.1 17W Isolated and Phase Dimming Application

Input: AC85 $V_{RMS}$  to 145 $V_{RMS}$ , Output: 470mA/32V to 42V, Ta = +25°C

Figure 10-1 17W EVB Schematic

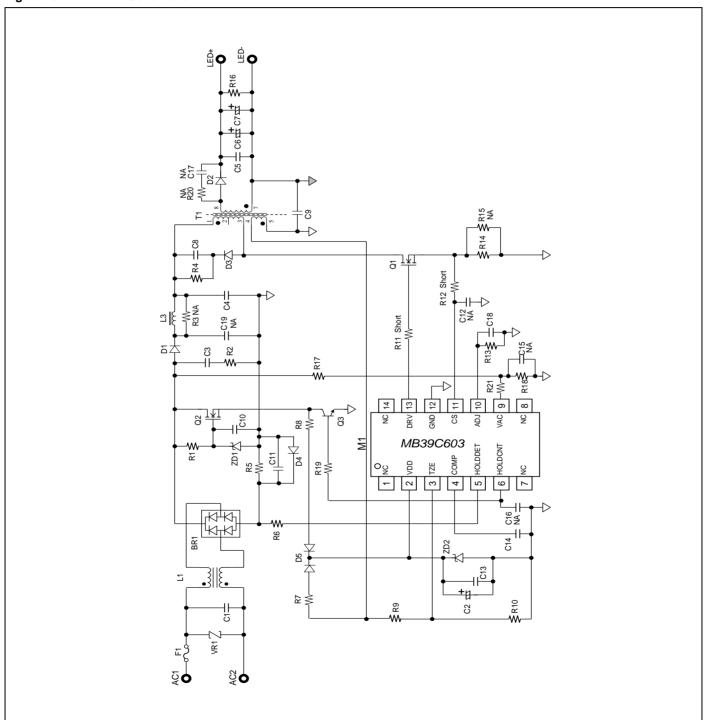




Table 10-1 17W BOM List

No.	Component	Description	Part No.	Vendor
1	M1	LED driver IC, SOP-14	MB39C603	Cypress
2	Q1	MOSFET, N-channel, 800V, 5.5A, TO-220F	FQPF8N80C	Fairchild
3	Q2	MOSFET, N-channel, 650V, 7.3A, TO-220	FDPF10N60NZ	Fairchild
4	Q3	Bipolar transistor, NPN, 60V, 3A, hfe = 250min, SOT-223	NZT560A	Fairchild
5	BR1	Bridge rectifier, 1A, 600V, Micro-DIP	MDB6S	Fairchild
6	D1	Diode, ultra fast rectifier, 1A, 600V, SMA	ES1J	Fairchild
7	D2	Diode, ultra fast rectifier, 3A, 200V, SMC	ES3D	Fairchild
8	D3	Diode, fast rectifier, 1A, 800V, SMA	RS1K	Fairchild
9	D4	Diode, ultra fast rectifier, 1A, 200V, SMA	ES1D	Fairchild
10	D5	Diode, 200 mA, 200V, SOT-23	MMBD1404	Fairchild
11	ZD1, ZD2	Diode, Zener, 18V, 500 mW, SOD-123	MMSZ18T1G	ON Semi
12	T1	Transformer, 600 µH	EI-2520	-
13	L1	Common mode inductor, 20 mH, 0.5A	744821120	Wurth Electronic
14	L3	Inductor, 3.3 mH, 0.27A, 5.0Ω, φ10×14.4	RCH114NP-332KB	Sumida
15	C1	Capacitor, X2, 305VAC, 0.1 µF	B32921C3104M	EPCOS
16	C2	Capacitor, aluminum electrolytic, 100 μF, 25V, φ6.3×11	EKMG250ELL101MF11D	NIPPON-CHEMI-CO N
17	C3	Capacitor, polyester film, 220 nF, 400V, 18.5×5.9	ECQ-E4224KF	Panasonic
18	C4	Capacitor, polyester film, 100 nF, 400V, 12×6.3	ECQ-E4104KF	Panasonic
19	C5	Capacitor, ceramic, 10 µF, 50V, X7S, 1210	-	-
20	C6, C7	Capacitor, aluminum electrolytic, 470 μF 50V, φ10.0×20	EKMG500ELL471MJ20S	NIPPON-CHEMI-CO N
21	C8	Capacitor, ceramic, 15 nF, 250V, X7R, 1206	-	-
22	C9	Capacitor, ceramic, 2.2 nF, X1/Y1 radial	DE1E3KX222M	muRata
23	C10, C11	Capacitor, ceramic, 0.1 µF, 50V, X5R, 0603	-	-
24	C12, C15, C16	NA (Open), 0603	-	-
25	C13	Capacitor, ceramic, 10 µF, 35V, X5R, 0805	-	-
26	C14	Capacitor, ceramic, 4.7 µF, 16V, JB, 0805	-	-
27	C17	NA (Open), 1206	-	-
28	C18	Capacitor, ceramic, 100 pF, 50V, CH, 0603	-	-
29	C19	NA (Open)	-	-
30	R1, R17	Resistor, chip, 1 MΩ, 1/4W, 1206	-	-
31	R2	Resistor, metal film, 510Ω, 2W,	-	-
32	R3	NA (Open), 1206	-	-
33	R4	Resistor, metal oxide film, 68 kΩ, 3W	-	-
34	R5	Resistor, chip, 5.1Ω, 1W, 2512	-	-
35	R6	Resistor, chip, 62 kΩ, 1/10W, 0603	-	-
36	R7	Resistor, chip, 10Ω, 1/8W, 0805	-	-
37	R8	Resistor, chip, 22Ω, 1/10W, 0603	-	-
38	R9	Resistor, chip, 91 kΩ, 1/10W, 0603	-	-
39	R10	Resistor, chip, 24 kΩ, 1/10W, 0603	-	-
40	R11, R12	NA (Short), 0603	-	-
41	R13 R14	Resistor, chip, 39 kΩ, 1/10W, 0603 Resistor, chip, 1.1Ω, 1/4W, 1206	-	-
42	R14	Resistor, chip, 1.1Ω, 1/4W, 1206  Resistor, chip, 51 kΩ, 1/10W, 0603	-	-
44	R18	Resistor, chip, 33 k $\Omega$ , 1/10W, 0603	-	-
45	R19	Resistor, chip, 12 kΩ, 1/10W, 0603	-	-
46	R20, R15	NA (Open), 1206	-	-
47	R21	Resistor, chip, 510 kΩ, 1/10W, 0603	-	
48	VR1	Varistor, 275VAC, 7 mm DISK	ERZ-V07D431	Panasonic
49	F1	Fuse, 1A, 300VAC	3691100000	Littelfuse



Fairchild : Fairchild Semiconductor International, Inc.

On Semi : ON Semiconductor

Wurth Electronic : Wurth Electronics Midcom Inc.
Sumida : SUMIDA CORPORATION

EPCOS : EPCOS AG

NIPPON-CHEMI-CON : Nippon Chemi-Con Corporation

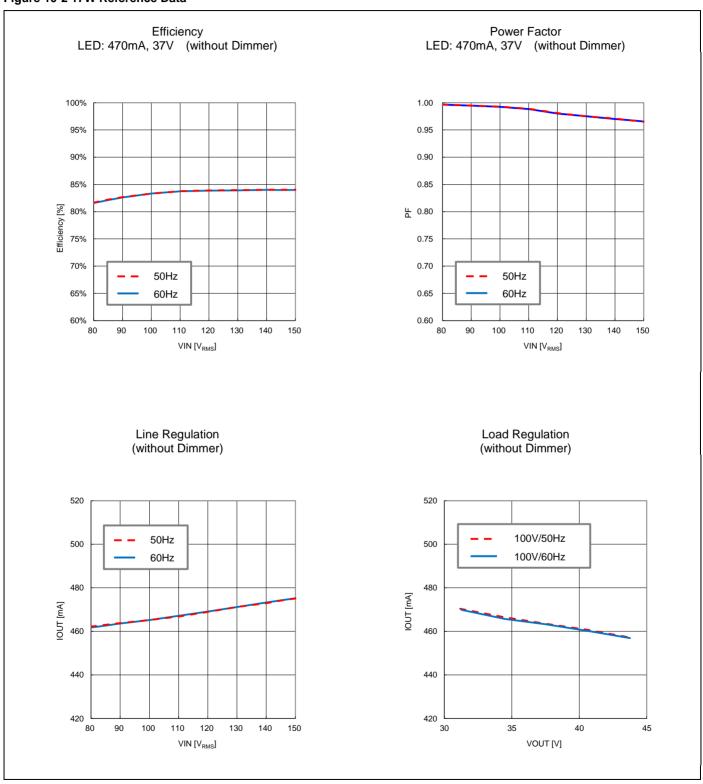
Panasonic : Panasonic Corporation

muRata : Murata Manufacturing Co., Ltd.

Littelfuse : Littelfuse, Inc.



Figure 10-2 17W Reference Data





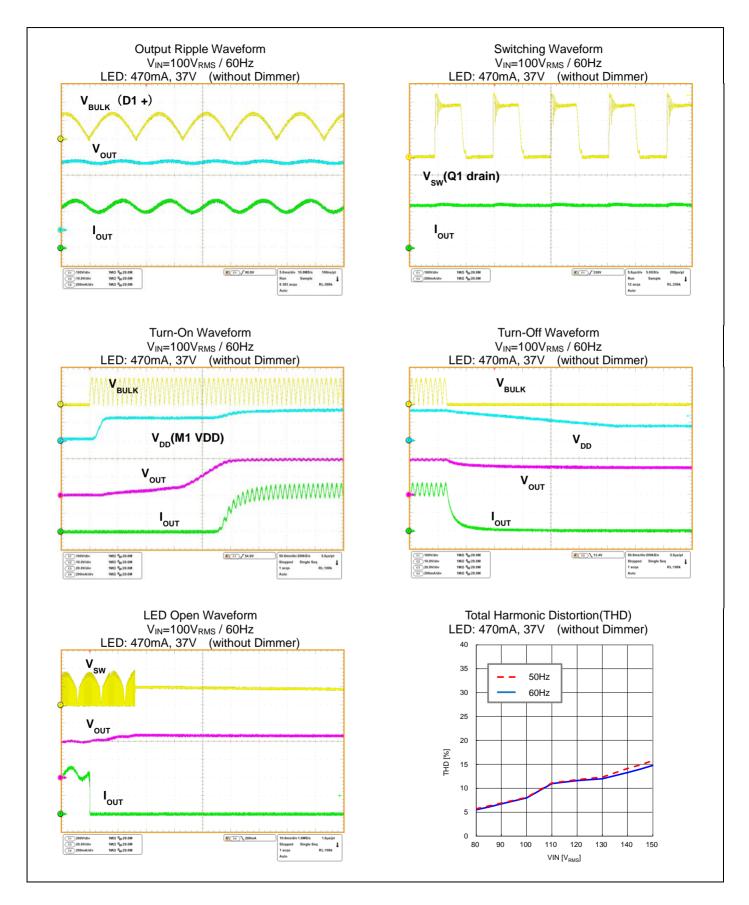
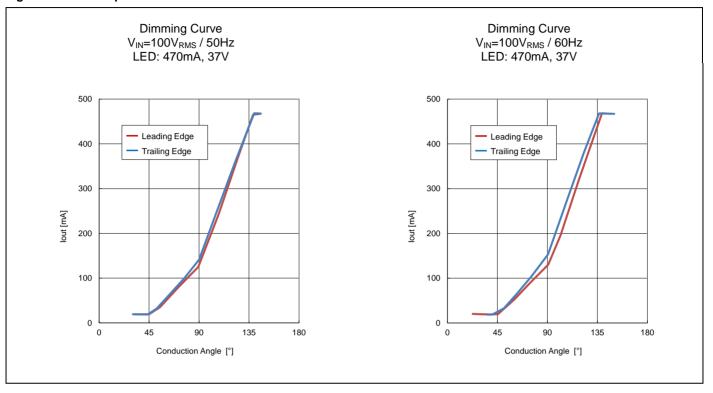




Figure 10-3 17W Japan Dimmer Performance Data

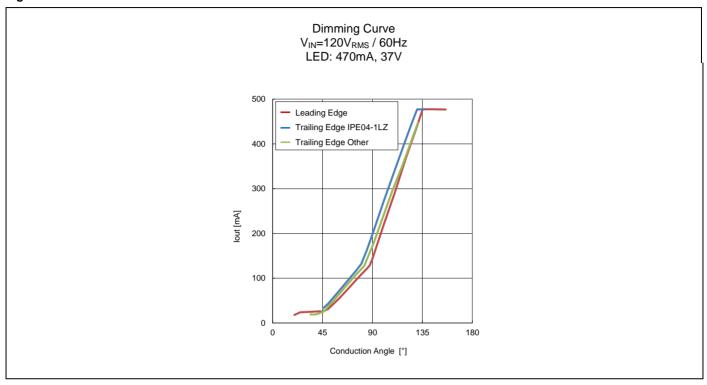


**Table 10-2 17W Japan Dimmer Performance Data** 

D	immer	Input		Minimum	Minimum	Maximu	Maximu
Vendor	Parts Name	Condition	Туре	Angle (°)	I <sub>OUT</sub> (mA)	m Angle (°)	m l <sub>out</sub> (mA)
LUTRON	DVCL-123P-JA			31.9	19.2	141.8	468.4
	WTC57521			38.0	19.2	145.6	467.6
Panasonic	WN575280K			27.7	19.8	147.2	467.0
	NQ20203T	VIN=100V <sub>RMS</sub>	Leading Edge	31.0	19.4	146.7	466.9
DAIKO	DP-37154	50Hz (Japan Dimmer)	Leading Edge	32.4	19.1	142.9	466.9
Mitsubishi	DEM1003B			28.3	19.7	147.8	466.9
	DG9022H			46.4	19.4	151.9	467.2
TOSHIBA	DG9048N			34.0	19.2	155.3	466.6
	WDG9001		Trailing Edge	30.4	18.8	145.4	468.4
LUTRON	DVCL-123P-JA			22.7	19.1	138.5	468.7
	WTC57521			38.9	19.1	146.7	468.4
Panasonic	WN575280K			27.4	19.6	146.2	466.8
	NQ20203T	VIN=100V <sub>RMS</sub>	Leading Edge	27.6	19.6	144.3	467.3
DAIKO	DP-37154	60Hz	Leading Lage	33.0	19.1	144.3	467.0
Mitsubishi	DEM1003B	(Japan Dimmer)		25.9	19.9	145.2	467.2
	DG9022H	1		22.0	18.8	150.8	467.0
TOSHIBA	DG9048N			22.7	19.6	153.6	466.5
	WDG9001	]	Trailing Edge	35.9	18.7	150.1	468.3



Figure 10-4 17W USA Dimmer Performance Data

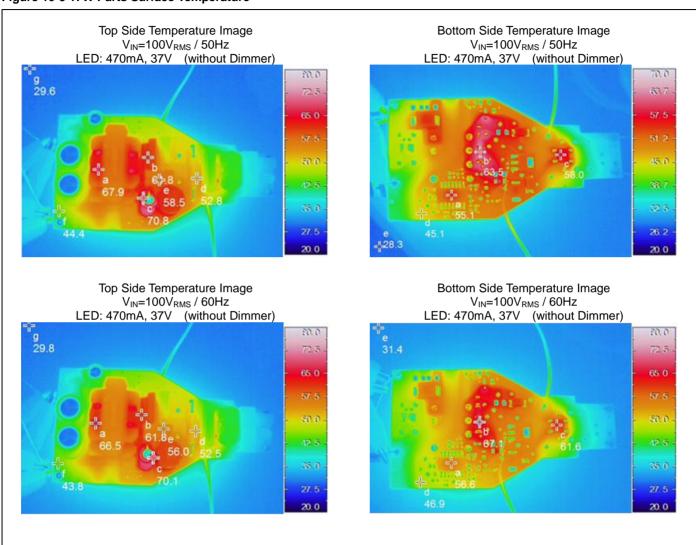


**Table 10-3 17W USA Dimmer Performance Data** 

Dimmer		Input		Minimum	Minimum	Maximu	Maximu
Vendor	Parts Name	Condition	Туре	Angle (°)	I <sub>OUT</sub> (mA)	m Angle (°)	m l <sub>out</sub> (mA)
	IPI06-1LZ			42.3	25.3	156.0	477.5
LEVITON	6631-LW			21.8	20.1	144.1	470.2
LLVIION	6641-W			39.1	19.5	147.7	471.5
	6683			35.2	19.5	155.5	468.9
	SLV-600-WH			19.7	18.0	135.4	454.2
	S-600P-WH			35.0	19.5	137.6	470.6
	TG-600PH-WH			45.4	19.8	140.4	470.5
	AY-600P-WH			40.2	19.5	143.6	470.6
	GL-600H-DK			25.1	20.0	135.9	457.3
	TG-600PNLH-WH	VIN=120V <sub>RMS</sub>	Leading Edge	34.1	19.5	141.0	470.8
LUTRON	TGCL-153PH-WH			33.3	19.4	135.0	455.4
LOTRON	TT-300NLH-WH	60Hz		41.7	19.5	143.2	470.5
	DV-603PG-WH	(USA Dimmer)		35.6	19.4	116.4	316.5
	DVCL-153-WH			38.0	19.4	133.9	445.7
	DV603PH-WH			33.0	19.5	136.9	471.2
	LGCL-153PLH-WH			39.3	19.2	133.9	444.4
	D-603PH			24.2	20.0	133.5	439.1
	DV-600PH-WH			32.8	19.3	139.3	470.7
GE	52129			23.8	20.2	157.0	469.8
GE	18023			36.9	19.4	158.5	469.5
LEVITON	IPE04-1LZ			45.6	33.1	136.9	477.3
LUTRON	SELV-300P-WH		Trailing Edge	34.1	19.1	130.9	447.2
LUTRON	DVELV-300P-WH			34.1	19.0	131.8	455.2



Figure 10-5 17W Parts Surface Temperature



**Table 10-4 17W Parts Surface Temperature Data** 

Side	Cursor Point		Surface Temperature [°C]		ΔTemperature [Δ°C]	
Oldo		Cursor rount	50Hz	60Hz	50Hz	60Hz
	а	T2	68.0	66.5	38.3	36.8
	b	Q1	61.8	61.8	32.2	32.0
	С	R4	70.8	70.1	41.2	40.3
Тор	d	R2	52.8	52.5	23.1	22.8
	е	Q2	58.5	56.0	28.9	26.2
	f	PCB	44.5	43.8	14.8	14.0
	g	Out of PCB	29.6	29.8	-	-
	а	M1	55.1	56.6	26.8	25.2
	b	Back side of R4	63.5	67.1	35.2	35.8
Bottom	С	BR1	58.0	61.6	29.7	30.2
	d	PCB	45.1	46.9	16.7	15.5
	е	Out of PCB	28.3	31.4	-	-



## 11. Usage Precautions

#### Do not configure the IC over the maximum ratings.

If the IC is used over the maximum ratings, the LSI may be permanently damaged.

It is preferable for the device to normally operate within the recommended usage conditions. Usage outside of these conditions can have an adverse effect on the reliability of the LSI.

#### Use the device within the recommended operating conditions.

The recommended values guarantee the normal LSI operation under the recommended operating conditions.

The electrical ratings are guaranteed when the device is used within the recommended operating conditions and under the conditions stated for each item.

### Take appropriate measures against static electricity.

- Containers for semiconductor materials should have anti-static protection or be made of conductive material.
- ■After mounting, printed circuit boards should be stored and shipped in conductive bags or containers.
- ■Work platforms, tools, and instruments should be properly grounded.
- ■Working personnel should be grounded with resistance of 250 k $\Omega$  to 1 M $\Omega$  in serial between body and ground.

### Do not apply negative voltages.

The use of negative voltages below - 0.3 V may make the parasitic transistor activated to the LSI, and can cause malfunctions.



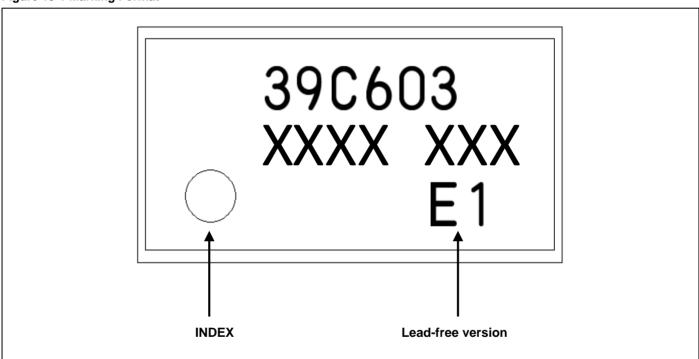
## 12. Ordering Information

**Table 12-1 Ordering Information** 

Part Number	Package	Shipping Form
MB39C603PF-G-JNEFE1	14-pin plastic SOP	Emboss
MB39C603PF-G-JNE1	(FPT-14P-M04)	Tube

## 13. Marking Format

Figure 13-1 Marking Format





## 14. Recommended Mounting Condition [JEDEC Level3] Lead Free

### 14.1 Recommended Reflow Condition

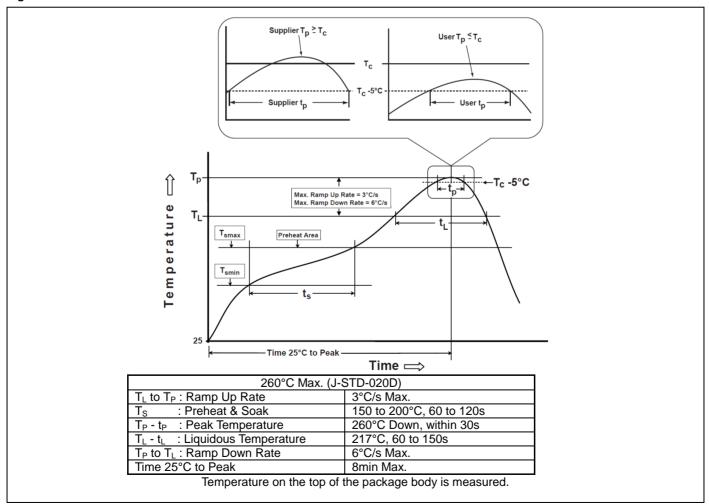
**Table 14-1 Recommended Reflow Condition** 

Items	Contents			
Method	IR(Infrared Reflow) / Convection			
Times	3 times in succession			
Floor life	Before unpacking	Please use within 2 years after production.		
	From unpacking to reflow	Within 7 days		
	In case over period of floor life(*1)	Baking with 125°C+/-3°C for 24hrs+2hrs/-0hrs is required. Then please use within 7 days. (Please remember baking is up to 2 times)		
Floor life	Between 5°C and 30°C and also below 60%RH required. (It is preferred lower humidity in the required temp			
condition	range.)			

<sup>\*1:</sup> Concerning the Tape & Reel product, please transfer product to heatproof tray and so on when you perform baking. Also please prevent lead deforming and ESD damage during baking process.

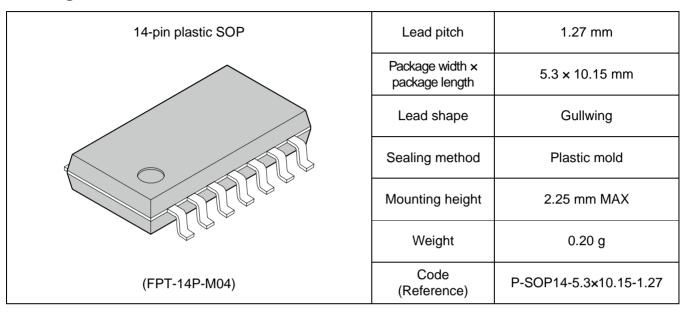
#### 14.2 Reflow Profile

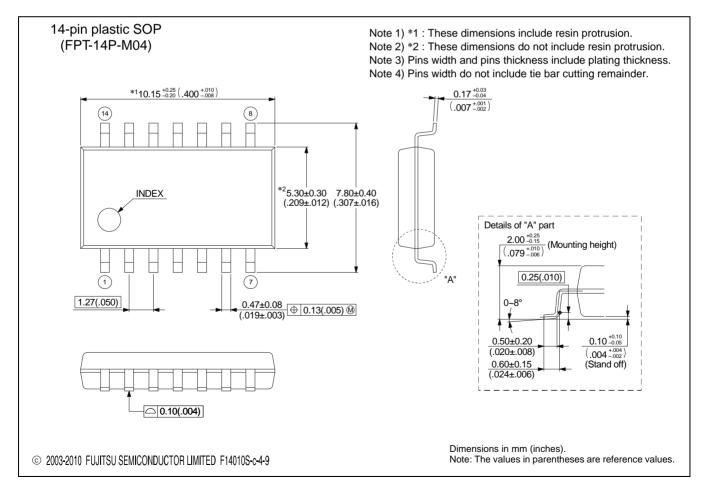
Figure 14-1 Reflow Profile





## 15. Package Dimensions







# 16. Major Changes

Spansion Publication Number: MB39C603\_DS405-00021

Page	Section	Descriptions		
Revision1.0	)			
-	-	Initial release		
Revision2.0				
7	7. Absolute Maximum Ratings	Removed ESD Voltage (Machine Model) from Table 7-1		

NOTE: Please see "Document History" about later revised information.



# **Document History**

Document Title: MB39C603 Phase Dimmable PSR LED Driver IC for LED Lighting

Document Number: 002-08450

Revision	ECN	Orig. of Change	Submission Date	Description of Change
**	-	тоуо	02/20/2015	Migrated to Cypress and assigned document number 002-08450.  No change to document contents or format.
*A	5211117	тоуо	04/07/2016	Updated to Cypress format.



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